

Features

- 30MHz -3dB bandwidth
- Supply voltage = 4.5V to 16.5V
- Low supply current (per amplifier) = 2.5mA
- High slew rate = 33V/ μ s
- Unity-gain stable
- Beyond the rails input capability
- Rail-to-rail output swing
- Available in both standard and space-saving fine pitch packages

Applications

- Driver for A-to-D Converters
- Data Acquisition
- Video Processing
- Audio Processing
- Active Filters
- Test Equipment
- Battery Powered Applications
- Portable Equipment

Ordering Information

Part No.	Package	Tape & Reel	Outline #
EL5210CS	SO-8	-	MDP0027
EL5210CS-T13	SO-8	13 in	MDP0027
EL5210CY	MSOP-8	-	MDP0043
EL5210CY-T7	MSOP-8	7 in	MDP0043
EL5210CY-T13	MSOP-8	13 in	MDP0043
EL5410CS	SO-14	-	MDP0027
EL5410CS-T13	SO-14	13 in	MDP0027
EL5410CR	TSSOP-14	-	MDP0044
EL5410CR-T7	TSSOP-14	7 in	MDP0044
EL5410CR-T13	TSSOP-14	13 in	MDP0044

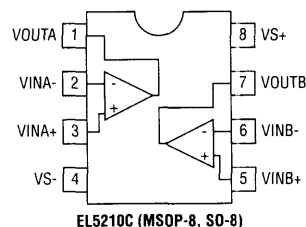
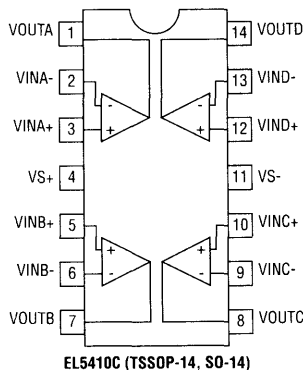
General Description

The EL5210C and EL5410C are low power, high voltage rail-to-rail input-output amplifiers. The EL5210C contains two amplifiers in one package and the EL5410C contains four amplifiers. Operating on supplies ranging from 5V to 15V, while consuming only 2.5mA per amplifier, the EL5410C and EL5210C have a bandwidth of 30MHz (-3dB). They also provide common mode input ability beyond the supply rails, as well as rail-to-rail output capability. This enables these amplifiers to offer maximum dynamic range at any supply voltage.

The EL5410C and EL5210C also feature fast slewing and settling times, as well as a high output drive capability of 30mA (sink and source). These features make these amplifiers ideal for high speed filtering and signal conditioning application. Other applications include battery power, portable devices, and anywhere low power consumption is important.

The EL5410C is available in a space-saving 14-Pin TSSOP package, as well as the industry-standard 14-Pin SO. The EL5210C is available in the 8-Pin MSOP and 8-Pin SO packages. Both feature a standard operational amplifier pin out. These amplifiers operate over a temperature range of -40°C to +85°C.

Connection Diagram



EL5210C, EL5410C

30MHz Rail-to-Rail Input-Output Op Amps

EL5210C, EL5410C

Amplifiers

Absolute Maximum Ratings (T_A = 25°C)

Values beyond absolute maximum ratings can cause the device to be prematurely damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Supply Voltage between V _{S+} and V _{S-}	+18V
Input Voltage	V _{S-} - 0.5V, V _S +0.5V
Maximum Continuous Output Current	30mA

Maximum Die Temperature	+125°C
Storage Temperature	-65°C to +150°C
Operating Temperature	-40°C to +85°C
Power Dissipation	See Curves
ESD Voltage	2kV

Important Note:

All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: T_J = T_C = T_A

Electrical Characteristics

V_{S+} = +5V, V_{S-} = -5V, R_L = 1kΩ and C_L = 12pF to 0V, T_A = 25°C unless otherwise specified.

Parameter	Description	Condition	Min	Typ	Max	Unit
Input Characteristics						
V _{OS}	Input Offset Voltage	V _{CM} = 0V		3	15	mV
TCV _{OS}	Average Offset Voltage Drift ^[1]			7		μV/°C
I _B	Input Bias Current	V _{CM} = 0V		2	60	nA
R _{IN}	Input Impedance			1		GΩ
C _{IN}	Input Capacitance			2		pF
CMIR	Common-Mode Input Range		-5.5		+5.5	V
CMRR	Common-Mode Rejection Ratio	for V _{IN} from -5.5V to 5.5V	50	70		dB
A _{VOL}	Open-Loop Gain	-4.5V ≤ V _{OUT} ≤ 4.5V	65	80		dB
Output Characteristics						
V _{OL}	Output Swing Low	I _L = -5mA		-4.9	-4.8	V
V _{OH}	Output Swing High	I _L = 5mA	4.8	4.9		V
I _{SC}	Short Circuit Current			±120		mA
I _{OUT}	Output Current			±30		mA
Power Supply Performance						
PSRR	Power Supply Rejection Ratio	V _S is moved from ±2.25V to ±7.75V	60	80		dB
I _S	Supply Current (Per Amplifier)	No Load		2.5	3.75	mA
Dynamic Performance						
SR	Slew Rate ^[2]	-4.0V ≤ V _{OUT} ≤ 4.0V, 20% to 80%		33		V/μs
t _S	Settling to +0.1% (A _V = +1)	(A _V = +1), V _O = 2V Step		140		ns
BW	-3dB Bandwidth			30		MHz
GBWP	Gain-Bandwidth Product			20		MHz
PM	Phase Margin			50		°
CS	Channel Separation	f = 5MHz		110		dB
d _G	Differential Gain ^[3]	R _F = R _G = 1kΩ and V _{OUT} = 1.4V		0.12		%
d _p	Differential Phase ^[3]	R _F = R _G = 1kΩ and V _{OUT} = 1.4V		0.17		°

1. Measured over operating temperature range
2. Slew rate is measured on rising and falling edges
3. NTSC signal generator used

EL5210C, EL5410C**30MHz Rail-to-Rail Input-Output Op Amps****Electrical Characteristics**

$V_{S+} = 5V$, $V_{S-} = 0V$, $R_L = 1k\Omega$ and $C_L = 12pF$ to 2.5V, $T_A = 25^\circ C$ unless otherwise specified.

Parameter	Description	Condition	Min	Typ	Max	Unit
Input Characteristics						
V_{OS}	Input Offset Voltage	$V_{CM} = 2.5V$		3	15	mV
TCV_{OS}	Average Offset Voltage Drift ^[1]			7		$\mu V/^\circ C$
I_B	Input Bias Current	$V_{CM} = 2.5V$		2	60	nA
R_{IN}	Input Impedance			1		G Ω
C_{IN}	Input Capacitance			2		pF
CMIR	Common-Mode Input Range		-0.5		+5.5	V
CMRR	Common-Mode Rejection Ratio	for V_{IN} from -0.5V to 5.5V	45	66		dB
A_{VOL}	Open-Loop Gain	$0.5V \leq V_{OUT} \leq 4.5V$	65	80		dB
Output Characteristics						
V_{OL}	Output Swing Low	$I_L = -5mA$		100	200	mV
V_{OH}	Output Swing High	$I_L = 5mA$	4.8	4.9		V
I_{SC}	Short Circuit Current			± 120		mA
I_{OUT}	Output Current			± 30		mA
Power Supply Performance						
PSRR	Power Supply Rejection Ratio	V_S is moved from 4.5V to 15.5V	60	80		dB
I_S	Supply Current (Per Amplifier)	No Load		2.5	3.75	mA
Dynamic Performance						
SR	Slew Rate ^[2]	$1V \leq V_{OUT} \leq 4V$, 20% o 80%		33		V/ μs
t_S	Settling to +0.1% ($A_V = +1$)	($A_V = +1$), $V_O = 2V$ Step		140		ns
BW	-3dB Bandwidth			30		MHz
GBWP	Gain-Bandwidth Product			20		MHz
PM	Phase Margin			50		°
CS	Channel Separation	$f = 5MHz$		110		dB
d_G	Differential Gain ^[3]	$R_F = R_G = 1k\Omega$ and $V_{OUT} = 1.4V$		0.30		%
d_P	Differential Phase ^[3]	$R_F = R_G = 1k\Omega$ and $V_{OUT} = 1.4V$		0.66		°

1. Measured over operating temperature range
2. Slew rate is measured on rising and falling edges
3. NTSC signal generator used

EL5210C, EL5410C

30MHz Rail-to-Rail Input-Output Op Amps

Electrical Characteristics

$V_{S+} = 15V$, $V_{S-} = 0V$, $R_L = 1k\Omega$ and $C_L = 12pF$ to $7.5V$, $T_A = 25^\circ C$ unless otherwise specified.

Parameter	Description	Condition	Min	Typ	Max	Unit
Input Characteristics						
V_{OS}	Input Offset Voltage	$V_{CM} = 7.5V$		3	15	mV
TCV_{OS}	Average Offset Voltage Drift ^[1]			7		$\mu V/^\circ C$
I_B	Input Bias Current	$V_{CM} = 7.5V$		2	60	nA
R_{IN}	Input Impedance			1		$G\Omega$
C_{IN}	Input Capacitance			2		pF
CMIR	Common-Mode Input Range		-0.5		+15.5	V
CMRR	Common-Mode Rejection Ratio	for V_{IN} from -0.5V to 15.5V	53	72		dB
A_{VOL}	Open-Loop Gain	$0.5V \leq V_{OUT} \leq 14.5V$	65	80		dB
Output Characteristics						
V_{OL}	Output Swing Low	$I_L = -7.5mA$		170	350	mV
V_{OH}	Output Swing High	$I_L = 7.5mA$	14.65	14.83		V
I_{SC}	Short Circuit Current			± 120		mA
I_{OUT}	Output Current			± 30		mA
Power Supply Performance						
PSRR	Power Supply Rejection Ratio	V_S is moved from 4.5V to 15.5V	60	80		dB
I_S	Supply Current (Per Amplifier)	No Load		2.5	3.75	mA
Dynamic Performance						
SR	Slew Rate ^[2]	$1V \leq V_{OUT} \leq 14V$, 20% o 80%		33		V/ μs
t_S	Settling to +0.1% ($A_V = +1$)	($A_V = +1$), $V_O = 2V$ Step		140		ns
BW	-3dB Bandwidth			30		MHz
GBWP	Gain-Bandwidth Product			20		MHz
PM	Phase Margin			50		°
CS	Channel Separation	$f = 5MHz$		110		dB
d_G	Differential Gain ^[3]	$R_F = R_G = 1k\Omega$ and $V_{OUT} = 1.4V$		0.10		%
d_P	Differential Phase ^[3]	$R_F = R_G = 1k\Omega$ and $V_{OUT} = 1.4V$		0.11		°

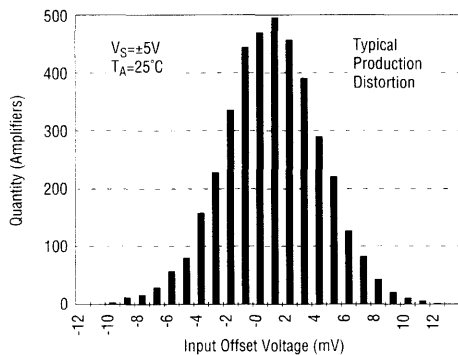
1. Measured over operating temperature range
2. Slew rate is measured on rising and falling edges
3. NTSC signal generator used

EL5210C, EL5410C

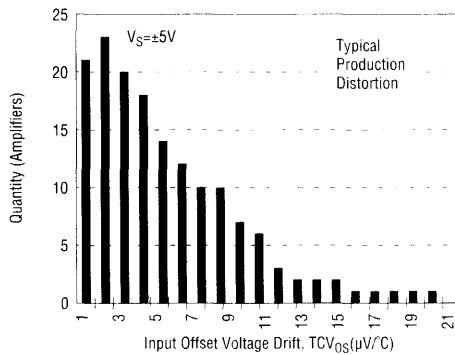
30MHz Rail-to-Rail Input-Output Op Amps

Typical Performance Curves

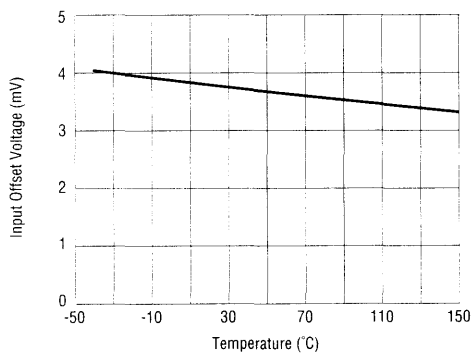
EL5410C Input Offset Voltage Distribution



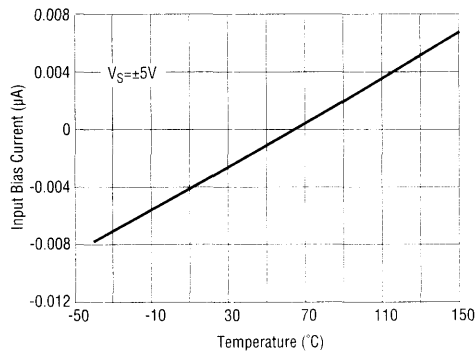
EL5410C Input Offset Voltage Drift



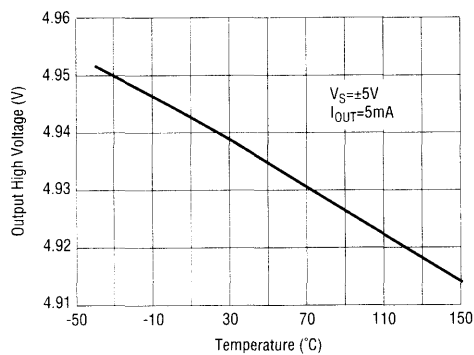
Input Offset Voltage vs Temperature



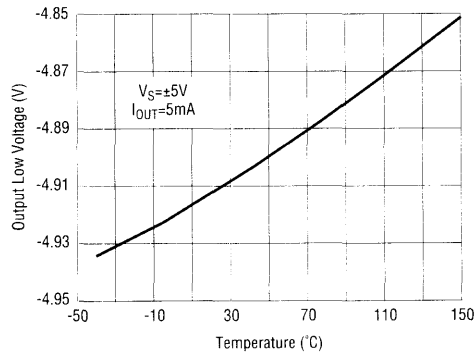
Input Bias Current vs Temperature



Output High Voltage vs Temperature



Output Low Voltage vs Temperature



EL5210C, EL5410C

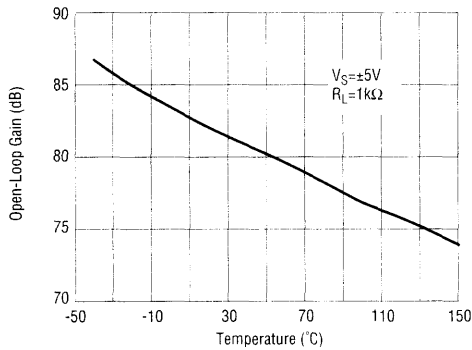
30MHz Rail-to-Rail Input-Output Op Amps

EL5210C, EL5410C

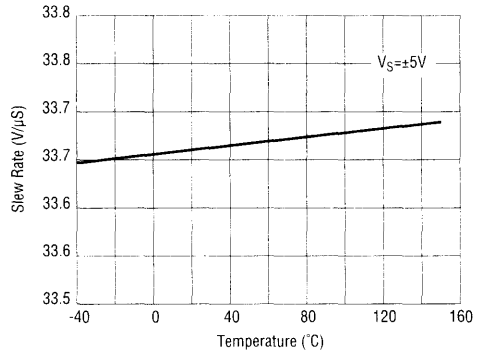
Amplifiers

Typical Performance Curves

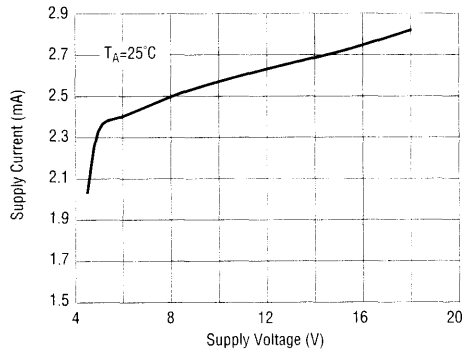
Open-Loop Gain vs Temperature



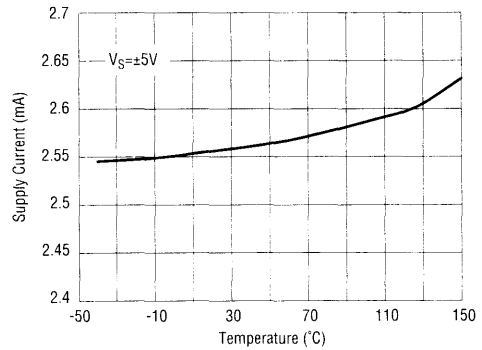
Slew Rate vs Temperature



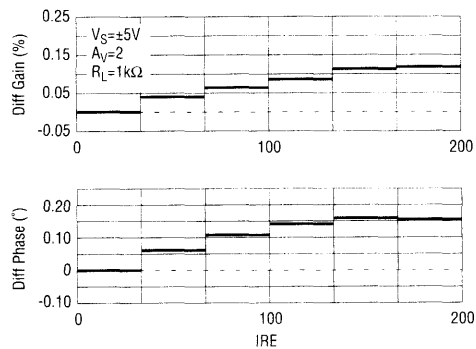
EL5410C Supply Current per Amplifier vs Supply Voltage



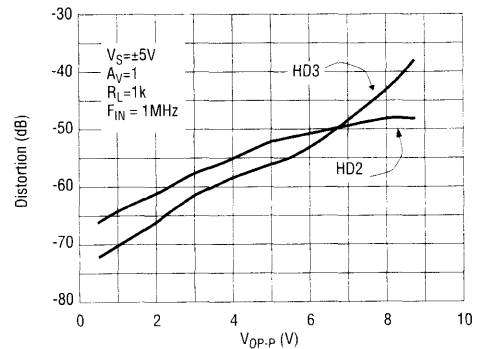
EL5410C Supply Current per Amplifier vs Temperature

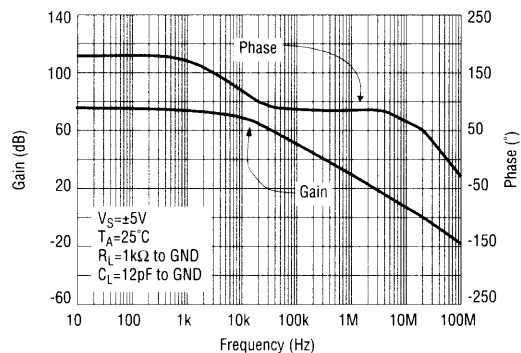
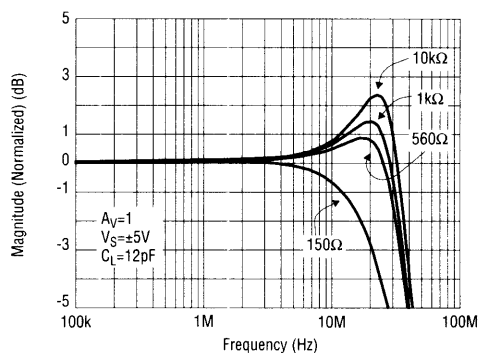
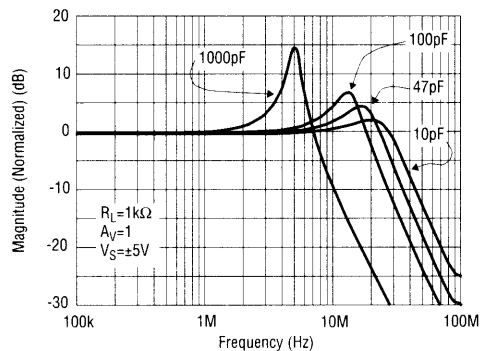
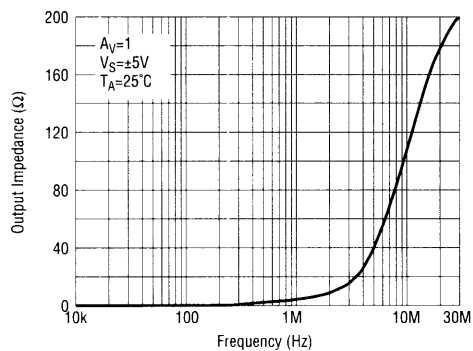
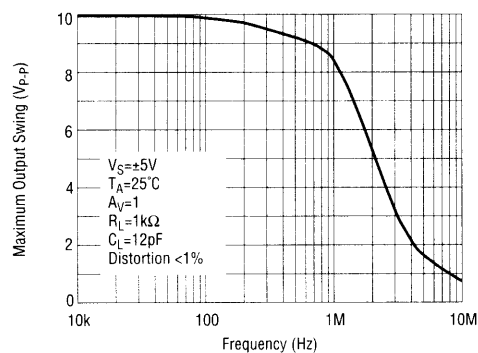
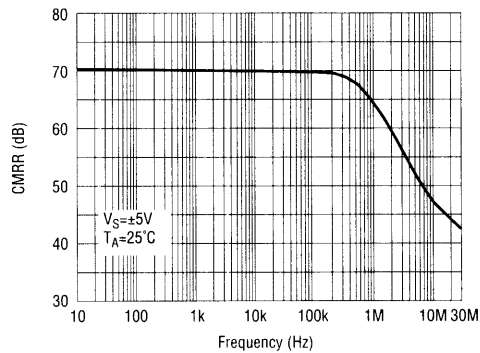


Differential Gain and Phase



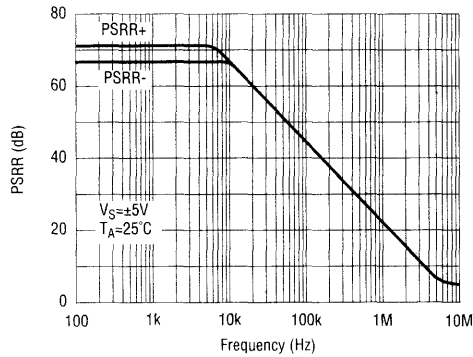
Harmonic Distortion vs V_{OP-P}



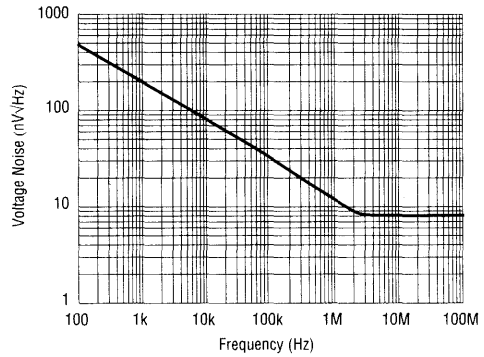
EL5210C, EL5410C**30MHz Rail-to-Rail Input-Output Op Amps****Typical Performance Curves****Open Loop Gain and Phase vs Frequency****Frequency Response for Various R_L** **Frequency Response for Various C_L** **Closed Loop Output Impedance vs Frequency****Maximum Output Swing vs Frequency****CMRR vs Frequency**

Typical Performance Curves

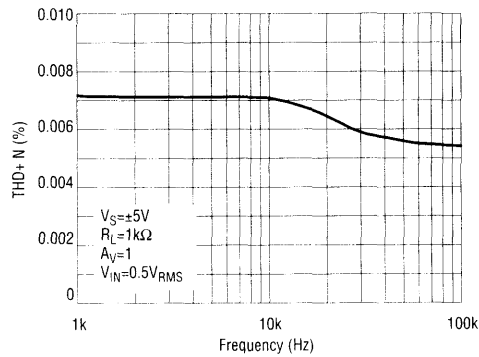
PSRR vs Frequency



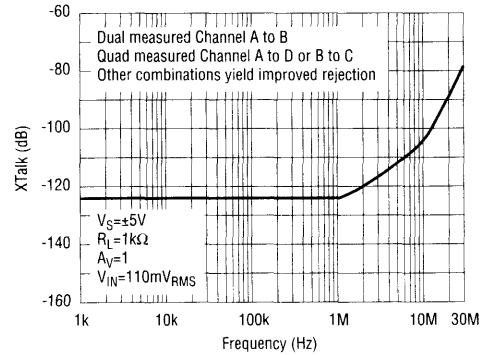
Input Voltage Noise Spectral Density vs Frequency



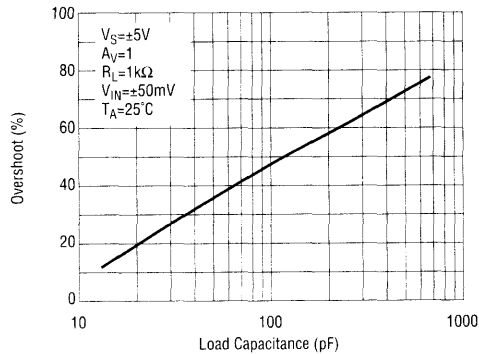
Total Harmonic Distortion + Noise vs Frequency



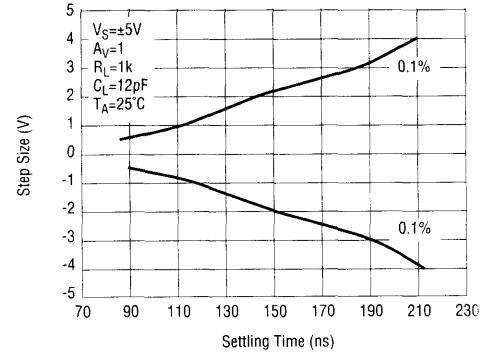
Channel Separation vs Frequency Response

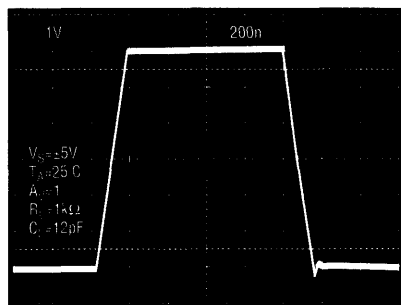
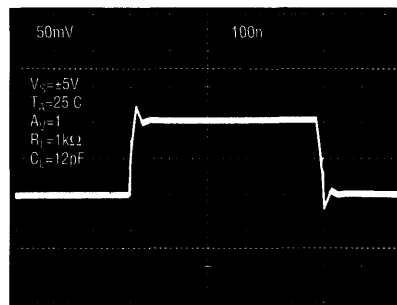


Small-Signal Overshoot vs Load Capacitance



Settling Time vs Step Size



EL5210C, EL5410C**30MHz Rail-to-Rail Input-Output Op Amps****Typical Performance Curves****Large Signal Transient Response****Small Signal Transient Response**

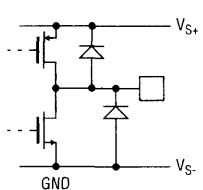
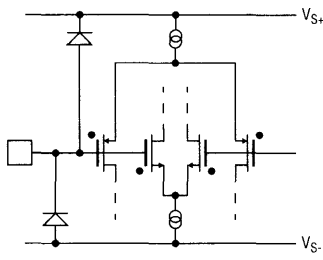
EL5210C, EL5410C

30MHz Rail-to-Rail Input-Output Op Amps

EL5210C, EL5410C

Amplifiers

Pin Descriptions

EL5210C	EL5410C	Name	Function	Equivalent Circuit
1	1	V_{OUTA}	Amplifier A Output	 <p>Circuit 1</p>
2	2	V_{INA-}	Amplifier A Inverting Input	 <p>Circuit 2</p>
3	3	V_{INA+}	Amplifier A Non-Inverting Input	(Reference Circuit 2)
8	4	V_{S+}	Positive Power Supply	
5	5	V_{INB+}	Amplifier B Non-Inverting Input	(Reference Circuit 2)
6	6	V_{INB-}	Amplifier B Inverting Input	(Reference Circuit 2)
7	7	V_{OUTB}	Amplifier B Output	(Reference Circuit 1)
	8	V_{OUTC}	Amplifier C Output	(Reference Circuit 1)
	9	V_{INC-}	Amplifier C Inverting Input	(Reference Circuit 2)
	10	V_{INC+}	Amplifier C Non-Inverting Input	(Reference Circuit 2)
4	11	V_{S-}	Negative Power Supply	
	12	V_{IND+}	Amplifier D Non-Inverting Input	(Reference Circuit 2)
	13	V_{IND-}	Amplifier D Inverting Input	(Reference Circuit 2)
	14	V_{OUTD}	Amplifier D Output	(Reference Circuit 1)

EL5210C, EL5410C

30MHz Rail-to-Rail Input-Output Op Amps

Applications Information

Product Description

The EL5210C and EL5410C voltage feedback amplifiers are fabricated using a high voltage CMOS process. They exhibit Rail-to-Rail input and output capability, are unity gain stable and have low power consumption (2.5mA per amplifier). These features make the EL5210C and EL5410C ideal for a wide range of general-purpose applications. Connected in voltage follower mode and driving a load of 1k Ω and 12pF, the EL5210C and EL5410C have a -3dB bandwidth of 30MHz while maintaining a 33V/ μ S slew rate. The EL5210C is a dual amplifier while the EL5410C is a quad amplifier.

Operating Voltage, Input, and Output

The EL5210C and EL5410C are specified with a single nominal supply voltage from 5V to 15V or a split supply with its total range from 5V to 15V. Correct operation is guaranteed for a supply range of 4.5V to 16.5V. Most EL5210C and EL5410C specifications are stable over both the full supply range and operating temperatures of -40°C to +85°C. Parameter variations with operating voltage and/or temperature are shown in the typical performance curves.

The input common-mode voltage range of the EL5210C and EL5410C extends 500mV beyond the supply rails. The output swings of the EL5210C and EL5410C typically extend to within 100mV of positive and negative supply rails with load currents of 5mA. Decreasing load currents will extend the output voltage range even closer to the supply rails. Figure 1 shows the input and output waveforms for the device in the unity-gain configuration. Operation is from ± 5 V supply with a 1k Ω load

connected to GND. The input is a 10Vp-p sinusoid. The output voltage is approximately 9.8Vp-p.

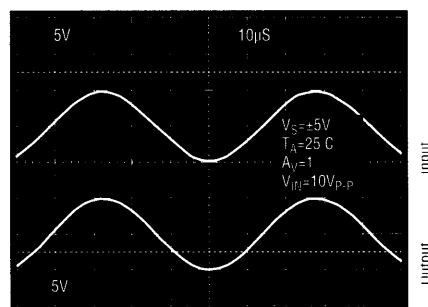


Figure 1. Operation with Rail-to-Rail Input and Output

Short Circuit Current Limit

The EL5210C and EL5410C will limit the short circuit current to ± 120 mA if the output is directly shorted to the positive or the negative supply. If an output is shorted indefinitely, the power dissipation could easily increase such that the device may be damaged. Maximum reliability is maintained if the output continuous current never exceeds ± 30 mA. This limit is set by the design of the internal metal interconnects.

Output Phase Reversal

The EL5210C and EL5410C are immune to phase reversal as long as the input voltage is limited from $V_S - 0.5$ V to $V_S + 0.5$ V. Figure 2 shows a photo of the output of the device with the input voltage driven beyond the supply rails. Although the device's output will not change phase, the input's overvoltage should be avoided. If an input voltage exceeds supply voltage by more than 0.6V, electrostatic protection diodes placed in the input stage

of the device begin to conduct and overvoltage damage could occur.

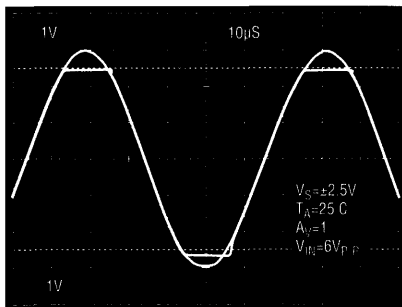


Figure 2. Operation with Beyond-the-Rails Input

Power Dissipation

With the high-output drive capability of the EL5210C and EL5410C amplifiers, it is possible to exceed the 125°C 'absolute-maximum junction temperature' under certain load current conditions. Therefore, it is important to calculate the maximum junction temperature for the application to determine if load conditions need to be modified for the amplifier to remain in the safe operating area.

The maximum power dissipation allowed in a package is determined according to:

$$P_{DMAX} = \frac{T_{JMAX} - T_{AMAX}}{\theta_{JA}}$$

Where:

- T_{JMAX} = Maximum Junction Temperature
- T_{AMAX} = Maximum Ambient Temperature
- θ_{JA} = Thermal Resistance of the Package
- P_{DMAX} = Maximum Power Dissipation in the Package.

The maximum power dissipation actually produced by an IC is the total quiescent supply current times the total power supply voltage, plus the power in the IC due to the loads, or:

$$P_{DMAX} = \sum i[V_S \times I_{SMAX} + (V_S - V_{OUTi}) \times I_{LOADi}]$$

when sourcing, and

$$P_{DMAX} = \sum i[V_S \times I_{SMAX} + (V_{OUTi} - V_S) \times I_{LOADi}]$$

when sinking.

Where:

- $i = 1$ to 2 for Dual and 1 to 4 for Quad
- V_S = Total Supply Voltage
- I_{SMAX} = Maximum Supply Current Per Amplifier
- V_{OUTi} = Maximum Output Voltage of the Application
- I_{LOADi} = Load current

If we set the two P_{DMAX} equations equal to each other, we can solve for R_{LOADi} to avoid device overheat. Figure 3 and Figure 4 provide a convenient way to see if the device will overheat. The maximum safe power dissipation can be found graphically, based on the package type and the ambient temperature. By using the previous equation, it is a simple matter to see if P_{DMAX} exceeds the device's power derating curves. To ensure proper operation, it is important to observe the recommended derating curves shown in Figure 3 and Figure 4.

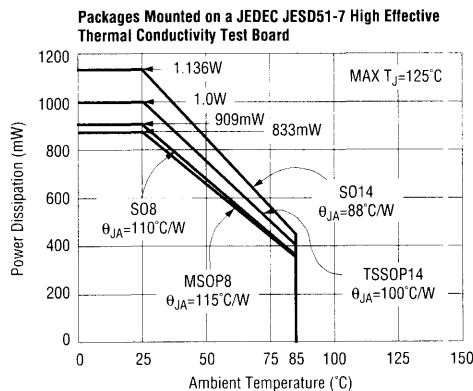


Figure 3. Package Power Dissipation vs Ambient Temperature

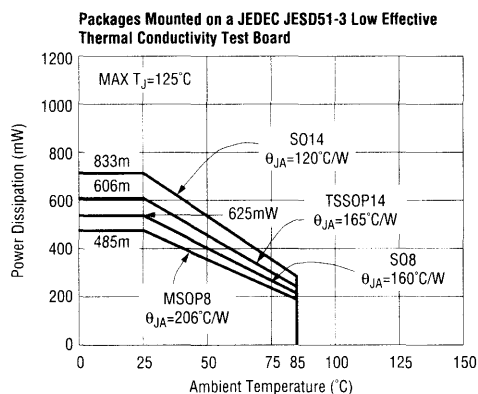
EL5210C, EL5410C**30MHz Rail-to-Rail Input-Output Op Amps**

Figure 4. Package Power Dissipation vs Ambient Temperature

Unused Amplifiers

It is recommended that any unused amplifiers in a dual and a quad package be configured as a unity gain follower. The inverting input should be directly connected to the output and the non-inverting input tied to the ground plane.

Driving Capacitive Loads

The EL5210C and EL5410C can drive a wide range of capacitive loads. As load capacitance increases, however, the -3dB bandwidth of the device will decrease and

the peaking increase. The amplifiers drive 10pF loads in parallel with 1k Ω with just 1.2dB of peaking, and 100pF with 6.5dB of peaking. If less peaking is desired in these applications, a small series resistor (usually between 5 Ω and 50 Ω) can be placed in series with the output. However, this will obviously reduce the gain slightly. Another method of reducing peaking is to add a "snubber" circuit at the output. A snubber is a shunt load consisting of a resistor in series with a capacitor. Values of 150 Ω and 10nF are typical. The advantage of a snubber is that it does not draw any DC load current or reduce the gain.

Power Supply Bypassing and Printed Circuit Board Layout

The EL5210C and EL5410C can provide gain at high frequency. As with any high-frequency device, good printed circuit board layout is necessary for optimum performance. Ground plane construction is highly recommended, lead lengths should be as short as possible and the power supply pins must be well bypassed to reduce the risk of oscillation. For normal single supply operation, where the V_{S-} pin is connected to ground, a 0.1 μF ceramic capacitor should be placed from V_{S+} to pin to V_{S-} pin. A 4.7 μF tantalum capacitor should then be connected in parallel, placed in the region of the amplifier. One 4.7 μF capacitor may be used for multiple devices. This same capacitor combination should be placed at each supply pin to ground if split supplies are to be used.